

BCR12LM-14LJ

700V - 12A - Triac Medium Power Use

R07DS0909EJ0100 Rev.1.00 Nov 14, 2012

Features

• I_{T (RMS)}: 12 A

 V_{DRM} : 800 V (Tj = 125°C)

Tj: 150°C

• I_{FGTI}, I_{RGTI}, I_{RGT III}:30 mA

Viso: 1800 V

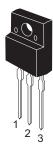
Insulated Type

Planar Passivation Type

UL Recognized: File No. E223904

Outline

RENESAS Package code: PRSS0003AF-A) (Package name: TO-220FL)





- 1. T₁ Terminal
- 2. T₂ Terminal3. Gate Terminal

Applications

Washing machine, inversion operation of capacitor motor, and other general controlling devices.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	Conditions
Farameter	Symbol	14	Onit	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V	Tj = 125°C
		700		Tj = 150°C
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	12	А	Commercial frequency, sine full wave 360° conduction, Tc = 93°C
Surge on-state current	I _{TSM}	120	А	60Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusion	l ² t	60	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass	_	1.5	g	Typical value
Isolation voltage Note5	Viso	1800	V	Ta = 25°C, AC 1 minute $T_1 \bullet T_2 \bullet G$ terminal to case

Electrical Characteristics

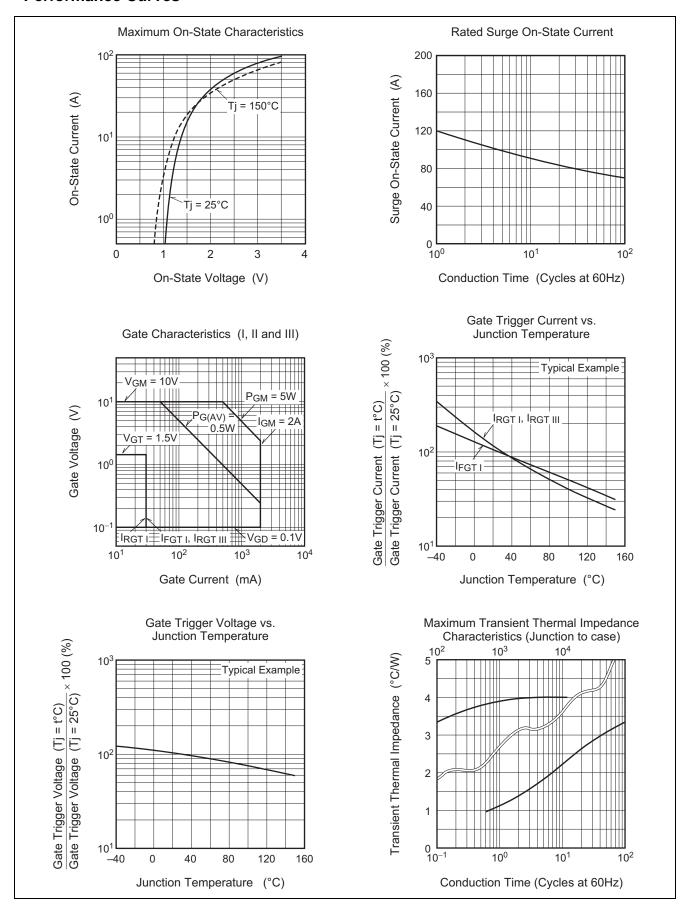
Parameter		Symbo	Rated value		Unit	Test conditions		
		ı	I Min. Typ. Max.	Offic				
Repetitive peak off-state current		I_{DRM}	_	_	2.0	mA	Tj = 150°C, V _{DRM} applied	
On-state voltage		V_{TM}	_	_	1.6	V	Tc = 25°C, I _{TM} = 20A, instantaneous measurement	
Gate trigger voltage ^{Note2}	I	V_{FGTI}	_	_	1.5	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,	
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$	
	III	V_{RGTIII}	_	_	1.5	V		
Gate trigger curent ^{Note2}	I	$I_{\text{FGT}_{\text{I}}}$	_	_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,	
	II	$I_{RGT_{\mathrm{I}}}$	_	_	30	mA	$R_G = 330 \Omega$	
	III	I_{RGTIII}	_	_	30	mA		
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$	
			0.1	_	_	V	$Tj = 150^{\circ}C, V_D = 1/2 V_{DRM}$	
Thermal resistance		R _{th (j-c)}			4.0	°C/W	Junction to case ^{Note3}	
Critical-rate of rise of off-state commutation voltage Note4		(dv/dt)c	10			V/μs	Tj = 125°C	
			1	_	_	V/μs	Tj = 150°C	

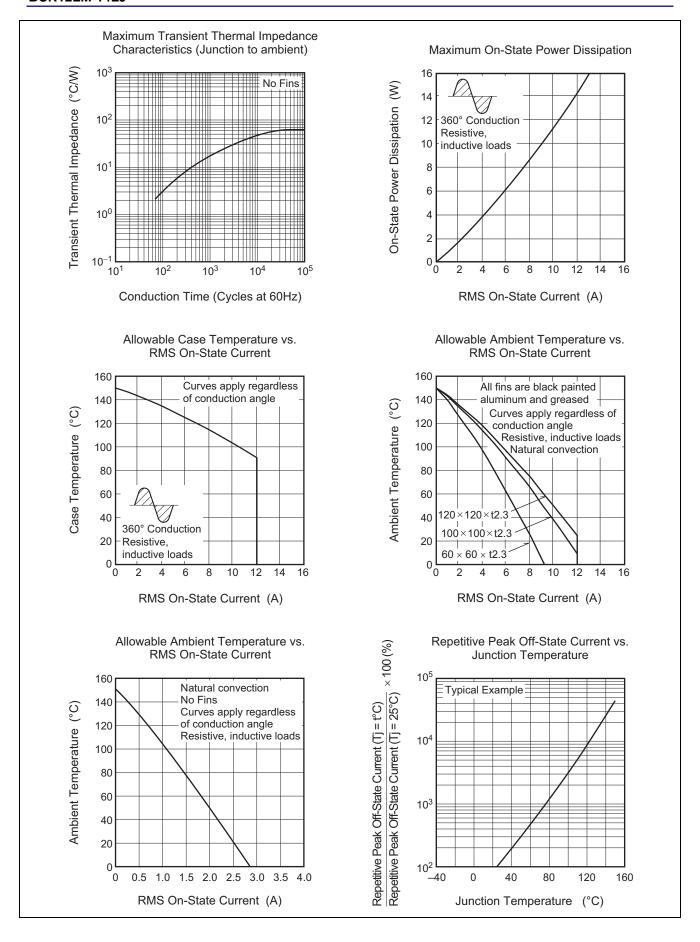
Notes: 1. Gate open.

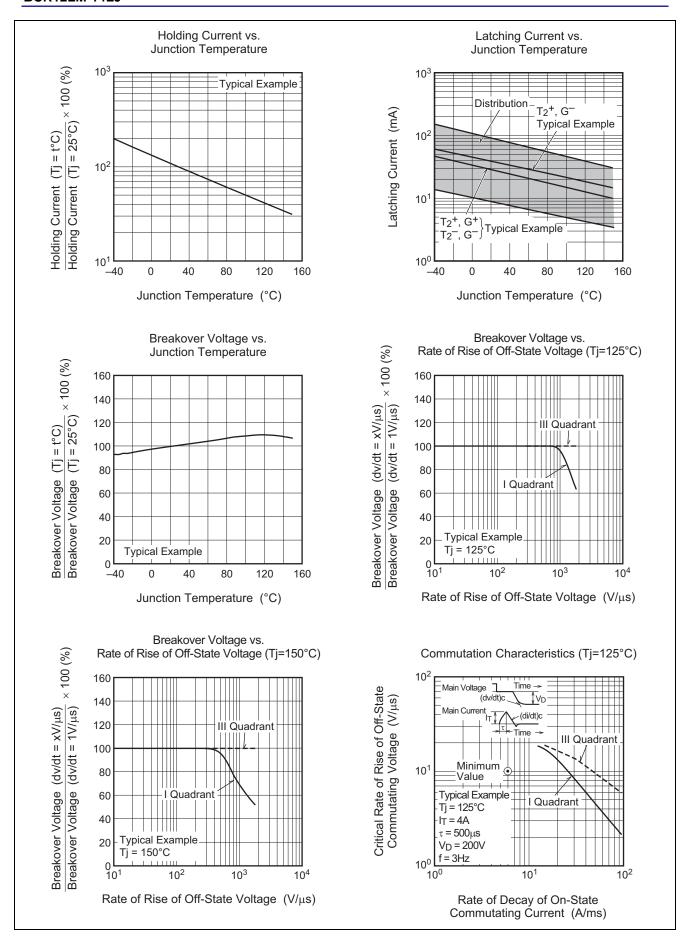
- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. The contact thermal resistance $R_{th\;(c\text{-}f)}$ in case of greasing is 0.5°C/W.
- 4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
- 5. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

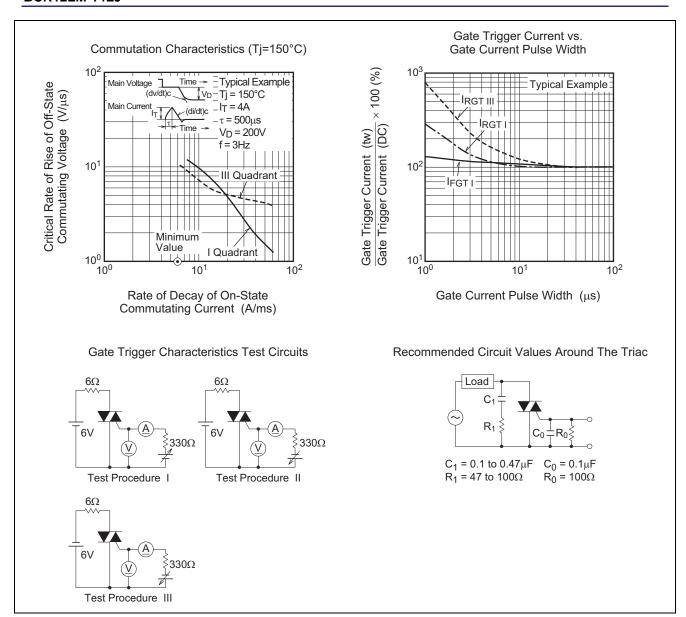
Test conditions	Commutating voltage and current waveforms (inductive load)			
1. Junction temperature Tj = 125/150°C	Supply Voltage → Time			
2. Rate of decay of on-state commutating current (di/dt)c = -6.0A/ms	Main Current → (di/dt)c → Time			
3. Peak off-state voltage $V_D = 400 \text{ V}$	Main Voltage Time (dv/df)c			

Performance Curves

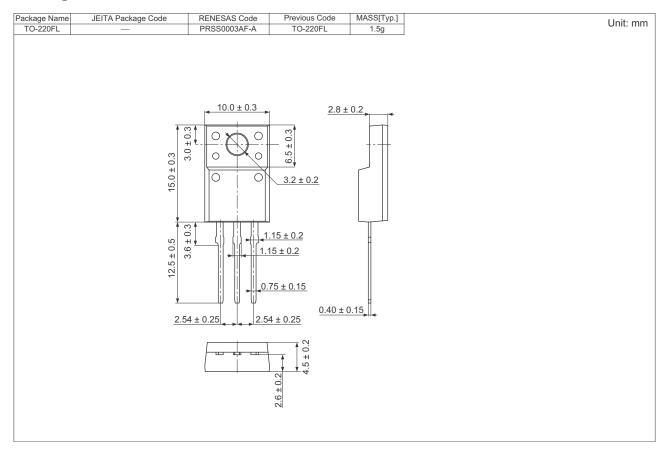








Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR12LM-14LJ#B00	Tube	50 pcs.	Straight type
BCR12LM-14LJA8#B00	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.

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